

Figure 1. The schematic diagram of the processing cycle of the atomic layer annealing and epitaxy (ALAE) technique.

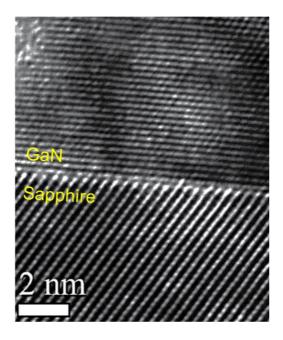


Figure 2. Cross-sectional HRTEM image of the GaN epilayer grown by ALAE.